

	<h2 style="color: red;">FQD8P10TM_F085</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">FQD8P10TM_F085</a></p> <hr/> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <hr/> <p><b>Teil der Beschreibung:</b> FQD8P10TM_F085 Fairchild/ON Semiconductor</p> <hr/> <p><b>Datenblätter:</b>  <a href="#">FQD8P10TM_F085.pdf</a></p> <hr/> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <hr/> <p><b>Lagerzustand:</b> New original, 22500 pcs Stock Available.</p> <hr/> <p><b>Liefern von:</b> Hong Kong</p> <hr/> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">FQD8P10TM_F085</a>
Hersteller	<a href="#">Fairchild/ON Semiconductor</a>
Beschreibung	FQD8P10TM_F085 Fairchild/ON Semiconductor
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	22500 pcs Stock
Serie	Automotive, AEC-Q101
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	D-Pak
Verlustleistung (max)	2.5W (Ta), 44W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	6.6A (Tc)
Rds On (Max) @ Id, Vgs	530 mOhm @ 3.3A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	470pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tape & Reel (TR)






FQD8P10TM\_F085 ist neu im Original, Suche FQD8P10TM\_F085 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQD8P10TM\_F085 Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQD8P10TM\_F085: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQD8P10TM_SB82052</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 100V 6.6A DPAK</p>	 <p><b>FQD9N08L</b> VB FQD9N08L VB</p>	 <p><b>FQD8P10TM_SB82052</b> Fairchild/ON Semiconductor MOSFET P-CH 100V 6.6A DPAK</p>	 <p><b>FQD8P10TM_</b> Fairchild/ON Semiconductor FQD8P10TM_ FAIRCHILD</p>
 <p><b>FQD8P10TM_F080</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 100V 6.6A DPAK</p>	 <p><b>FQD9N08TM</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 80V 7.4A DPAK</p>	 <p><b>FQD8P10TM-F085</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 100V 6.6A DPAK-3</p>	 <p><b>FQD9N08TM</b> Fairchild/ON Semiconductor MOSFET N-CH 80V 7.4A DPAK</p>

### heiße Teile

Mehr

 FQD6P25TM	 FQD6P25TM	 FQD7N10L	 FQD7N10LTF	 FQD7N10LTF
 FQD7N10LTM	 FQD7N10LTM	 FQD7N10TF	 FQD7N10TM	 FQD7N10TM
 FQD7N20L	 FQD7N20LTF	 FQD7N20LTF	 FQD7N20LTM	 FQD7N20LTM
 FQD7N20TF	 FQD7N20TF	 FQD7N20TM	 FQD7N20TM	 FQD7N30TM
 FQD7N30TM	 FQD7P06TF	 FQD7P06TF	 FQD7P06TM	 FQD7P06TM
 FQD7P06TM_F080	 FQD7P06TM_F080	 FQD7P06TM_NB82050	 FQD7P06TM_NB82050	 FQD7P10TF
 FQD7P20TF	 FQD7P20TF	 FQD7P20TM	 FQD7P20TM	 FQD7P20TM_F080
 FQD7P20TM_F080	 FQD8P10TF	 FQD8P10TF	 FQD8P10TF_NB82052	 FQD8P10TF_NB82052
 FQD8P10TM	 FQD8P10TM	 FQD8P10TM_	 FQD8P10TM_F080	 FQD8P10TM_F080
 FQD8P10TM_SB82052	 FQD8P10TM_SB82052	 FQD9N08L	 FQD9N25TM	 FQD9N25TM

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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